

isc Silicon NPN Darlington Power Transistor
2SD2079
DESCRIPTION

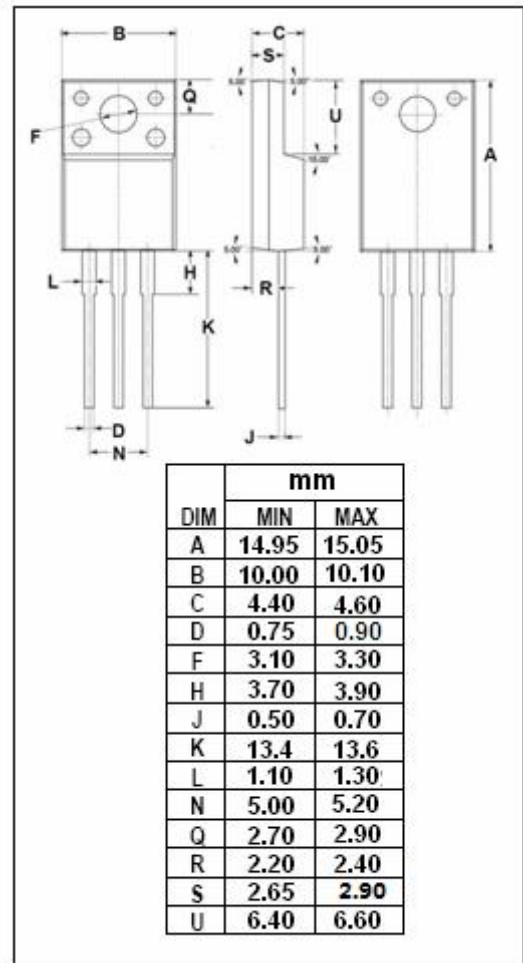
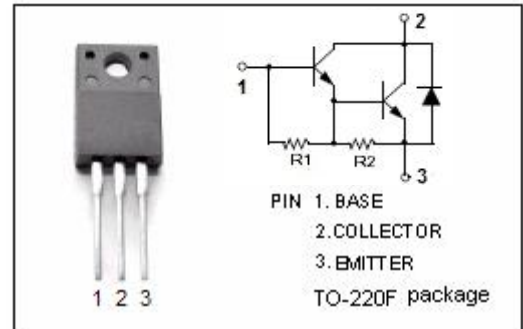
- Collector-Emitter Breakdown Voltage-
: $V_{(BR)CEO} = 100V(\text{Min})$
- High DC Current Gain-
: $h_{FE} = 2000(\text{Min})@ (V_{CE} = 3V, I_C = 3A)$
- Low Collector Saturation Voltage-
: $V_{CE(sat)} = 1.5V(\text{Max})@ (I_C = 3A, I_B = 6mA)$
- Complement to Type 2SB1381
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATIONS

- High power switching applications.
- Hammer drive, pulse motor drive applications.

ABSOLUTE MAXIMUM RATINGS($T_a=25^\circ\text{C}$)

SYMBOL	PARAMETER	VALUE	UNIT
V_{CBO}	Collector-Base Voltage	100	V
V_{CEO}	Collector-Emitter Voltage	100	V
V_{EBO}	Emitter-Base Voltage	7	V
I_C	Collector Current-Continuous	5	A
I_{CM}	Collector Current-Peak	8	A
I_B	Base Current-Continuous	0.5	A
P_C	Collector Power Dissipation @ $T_a=25^\circ\text{C}$	2	W
	Collector Power Dissipation @ $T_c=25^\circ\text{C}$	30	
T_J	Junction Temperature	150	$^\circ\text{C}$
T_{stg}	Storage Temperature	-55~150	$^\circ\text{C}$



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ELECTRICAL CHARACTERISTICS

T_j=25°C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	I _C = 30mA; I _B = 0	100			V
V _{CE(sat)-1}	Collector-Emitter Saturation Voltage	I _C = 3A; I _B = 6mA			1.5	V
V _{CE(sat)-2}	Collector-Emitter Saturation Voltage	I _C = 5A; I _B = 20mA			2.5	V
V _{BE(sat)}	Base-Emitter Saturation Voltage	I _C = 3A; I _B = 6mA			2.5	V
I _{CBO}	Collector Cutoff Current	V _{CB} = 100V; I _E = 0			100	μ A
I _{EBO}	Emitter Cutoff Current	V _{EB} = 6V; I _C = 0			2.5	mA
h _{FE-1}	DC Current Gain	I _C = 3A; V _{CE} = 3V	2000		15000	
h _{FE-2}	DC Current Gain	I _C = 5A; V _{CE} = 3V	1000			

Switching Times

t _{on}	Turn-on Time			1.0		μ s
t _{stg}	Storage Time	I _C = 3A, I _{B1} = I _{B2} = 6mA, V _{CC} ≈ 30V; R _L = 10 Ω		4.0		μ s
t _f	Fall Time			2.5		μ s

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